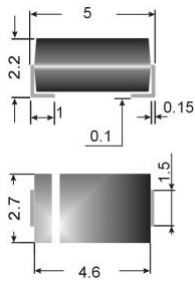


# S1 T ... S1 Y



## Surface mount diode

### Standard silicon rectifier diodes

#### S1 T ... S1 Y

**Forward Current: 1 A**

**Reverse Voltage: 1300 to 2000 V**

#### Features

- Max. solder temperature: 260 °C
- Plastic material has UL classification 94V-0

#### Mechanical Data

- Plastic case: SMA / DO-214AC
- Weight approx.: 0,07 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 7500 pieces per reel

1) Max. temperature of the terminals  $T_T = 100\text{ °C}$

2)  $I_F = 1\text{ A}$ ,  $T_J = 25\text{ °C}$

3)  $T_A = 25\text{ °C}$

4) Mounted on P.C. board with 25 mm<sup>2</sup> copper pads at each terminal

Type	Polarity color band	Repetitive peak reverse voltage $V_{RRM}$ V	Surge peak reverse voltage $V_{RSM}$ V	Maximum forward voltage $T_J = 25\text{ °C}$ $I_F = 1\text{ A}$ $V_F^{(2)}$ V	Maximum reverse recovery time $I_F = -\text{A}$ $I_R = -\text{A}$ $I_{RR} = -\text{A}$ $t_{rr}$ ns
S1 T	-	1300	1300	1,1	-
S1 W	-	1600	1600	1,1	-
S1 X	-	1800	1800	1,1	-
S1 Y	-	2000	2000	1,1	-

#### Absolute Maximum Ratings

$T_A = 25\text{ °C}$ , unless otherwise specified

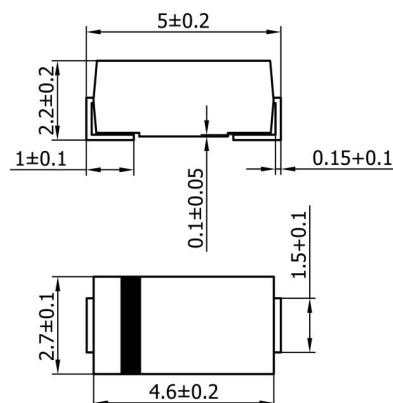
Symbol	Conditions	Values	Units
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_T = 100\text{ °C}$ <sup>1)</sup>	1	A
$I_{FRM}$	Repetitive peak forward current $f > 15\text{ Hz}$ <sup>1)</sup>	6	A
$I_{FSM}$	Peak fwd. surge current 50 Hz half sinus-wave <sup>3)</sup>	30	A
$I^2t$	Rating for fusing, $t < 10\text{ ms}$ <sup>3)</sup>	4,5	A <sup>2</sup> s
$R_{thA}$	Max. thermal resistance junction to ambient <sup>4)</sup>	70	K/W
$R_{thT}$	Max. thermal resistance junction to terminals	30	K/W
$T_J$	Operating junction temperature	-50 ... +150	°C
$T_s$	Storage temperature	-50 ... +150	°C

#### Characteristics

$T_A = 25\text{ °C}$ , unless otherwise specified

Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_J = 25\text{ °C}$ ; $V_R = V_{RRM}$ $T_J = 100\text{ °C}$ ; $V_R = V_{RRM}$	<5 <50	$\mu\text{A}$ $\mu\text{A}$
$C_J$	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
$Q_{rr}$	Reverse recovery charge ( $U_R = V$ ; $I_F = A$ ; $dI_F/dt = A/ms$ )	-	$\mu\text{C}$
$E_{RSM}$	Non repetitive peak reverse avalanche energy ( $L = \text{mH}$ ; $T_J = \text{°C}$ ; inductive load switched off)	-	mJ

Dimensions in mm



case: SMA / DO214AC



